COMPLIANT

HALOGEN

FREE



Vishay Semiconductors

Hyperfast Rectifier, 1 A FRED Pt®



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS			
I _{F(AV)}	1 A		
V_{R}	200 V		
V _F at I _F	0.68 V		
t _{rr}	25 ns		
T _J max.	175 °C		
Package	SMA (DO-214AC)		
Circuit configuration	Single		

FEATURES

- Hyperfast recovery time, reduced Q_{rr}, and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in snubber, boost, lighting, as high frequency rectifiers, and freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

MECHANICAL DATA

Case: SMA (DO-214AC)

Molding compound meets UL 94 V-0 flammability rating

Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V_{RRM}		200	V
Average rectified forward current	I _{F(AV)}	T _{Sp} = 158 °C	1	^
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C, 6 ms square pulse	50	A
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	200	-	-	
Forward voltage per diade	V	I _F = 1 A	-	0.82	0.90	V
Forward voltage, per diode	V_{F}	I _F = 1 A, T _J = 125 °C	-	0.68	0.76	
Reverse leakage current, per diode		V _R = V _R rated	-	-	2	μА
	I _R	$T_J = 125$ °C, $V_R = V_R$ rated	-	1	8	
Junction capacitance	C _T	V _R = 100 V	-	8	-	pF



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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, dI_F/dt =$	= 50 A/µs, V _R = 30 V	-	24	-	
Payaraa raaayary tima	t _{rr}	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		-	-	25	
Reverse recovery time		T _J = 25 °C		-	15.2	-	ns
		T _J = 125 °C		-	21	-	
Dealt recovery surrent		T _J = 25 °C	$I_F = 1 A$,	-	1.38	-	۸
Peak recovery current	I _{RRM}	T _J = 125 °C	$dI_F/dt = 200 \text{ A/}\mu\text{s},$ $V_R = 200 \text{ V}$	-	2	-	Α
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	10.6	-	nC
		T _J = 125 °C]	-	21	-	nc

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to mount	R_{thJM}	Device mounted on PCB with 2 x 3.5 mm soldering lands	-	11	21	°C/W
Thermal resistance, junction to ambient	R _{thJA}	Device mounted on PCB with recommended pad size	-	-	125	°C/W
Approximate weight				0.07		g
Approximate weight				0.002		oz.
Marking device		Case style SMA (DO-214AC)		1	H2	

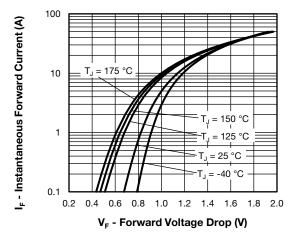


Fig. 1 - Typical Forward Voltage Drop Characteristics

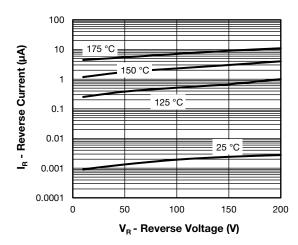


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



180

175

170

165

160

155

150 0

Allowable Case Temperature (°C)

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D = 0.02D = 0.05D = 0.1D = 0.2D = 0.5DC

2

2.5

3

3.5

1.5

 $I_{\text{F(AV)}}$ - Average Forward Current (A)

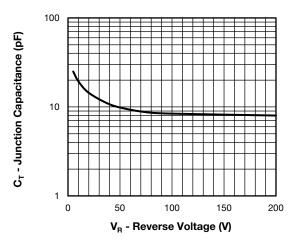
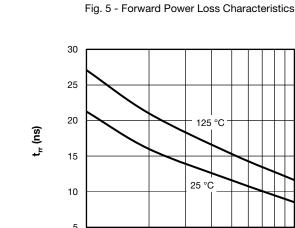


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

DC

0.8

1.2



3

2.5

2

1.5

0.5

0

0

0.5

Average Power Loss (W)

RMS limit

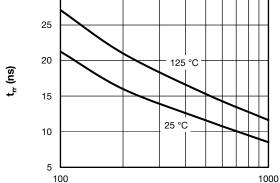


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

0.6

I_{F(AV)} - Average Forward Current (A)

Square wave (D = 0.50)Rated V_R applied

0.4

See note (1)

0.2

Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt

dl_F/dt (A/µs)

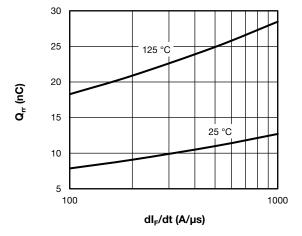
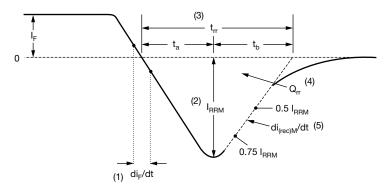


Fig. 7 - Typical Stored Charge vs. dl_F/dt

Note

 $^{(1)}$ Formula used: $T_{C} = T_{J}$ - (Pd + Pd_{REV}) x $R_{thJC};$ Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 5); Pd_{REV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = rated V_R

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- di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

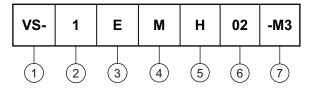
$$Q_{rr} = \frac{t_{rr} x I_{RRM}}{2}$$

(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 8 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- 2 Current rating (1 = 1 A)
- Circuit configuration:

E = single diode

4 - M = SMA package

5 - Process type,

H = hyperfast recovery

6 - Voltage code (02 = 200 V)

7 - -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-1EMH02-M3/5AT	7500	7500	13"diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95400</u>				
Part marking information	www.vishay.com/doc?95472			
Packaging information	www.vishay.com/doc?95404			
SPICE model	www.vishay.com/doc?96376			

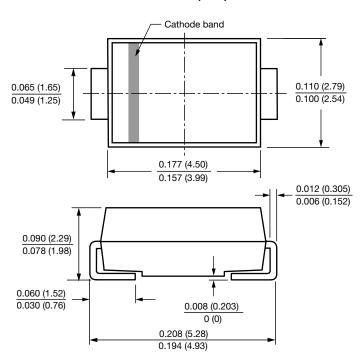


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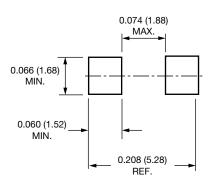
SMA

DIMENSIONS in inches (millimeters)

DO-214AC (SMA)



Mounting Pad Layout





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